

# DFM1200AXM45-TS001

## **Fast Recovery Diode Module**

DS6146-1 April 2014 (LN31501)

## **FEATURES**

- 10.2kV Isolation Package
- Low Reverse Recovery Charge •
- **High Switching Speed** •
- Low Forward Volt Drop •
- Isolated AISiC Base With AIN Substrates .
- Triple Diodes Can Be Paralleled For 3600A Rating

## **APPLICATIONS**

- **Chopper Diodes**
- Boost and Buck Converters
- **Free-wheel Circuits** .
- **Snubber Circuit**
- **Resonant Converters** •
- Induction Heating
- **Multi-level Switch Inverters**

The DFM1200AXM45-TS000 is a triple 4500V, fast recovery diode (FRD) module. Designed for low power loss, the module is suitable for a variety of high voltage applications in motor drives and power conversion.

Fast switching times and low reverse recovery losses allow high frequency operation, making the device suitable for the latest drive designs employing PWM and high frequency switching.

The module incorporates an electrically isolated base plate and low inductance construction enabling circuit designers to optimise circuit layouts and utilise grounded heat sinks for safety.

#### **ORDERING INFORMATION**

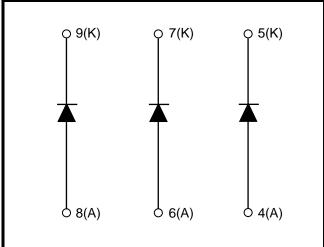
Order As:

#### DFM1200AXM45-TS000

Note: When ordering, please use the complete part number

## **KEY PARAMETERS**

V <sub>RRM</sub>		4500V
V <sub>F</sub>	(typ)	2.8V
I <sub>F</sub>	(max)	1200A
I <sub>FM</sub>	(max)	2400A



External connection required for a single 3600A diode

Fig. 1 Circuit configuration



Fig. 2 Package

#### **ABSOLUTE MAXIMUM RATINGS**

Stresses above those listed under 'Absolute Maximum Ratings' may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed. Exposure to Absolute Maximum Ratings may affect device reliability.

#### T<sub>case</sub> = 25°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
V <sub>RRM</sub>	Repetitive peak reverse voltage	T <sub>j</sub> = 125°C	4500	V
I <sub>F</sub>	Forward current (per arm)	DC, T <sub>case</sub> = 65°C	1200	А
I <sub>FM</sub>	Max. forward current	$T_{case} = 115^{\circ}C, t_{p} = 1ms$	2400	А
l <sup>2</sup> t	I <sup>2</sup> t value fuse current rating	$V_R = 0, t_p = 10ms, T_j = 125^{\circ}C$	460	kA <sup>2</sup> s
P <sub>max</sub>	Max. power dissipation	$T_{case} = 25^{\circ}C, T_j = 125^{\circ}C$	6250	W
V <sub>isol</sub>	Isolation voltage – per module	Commoned terminals to base plate. AC RMS, 1 min, 50Hz	10.2	kV
Q <sub>PD</sub>	Partial discharge – per module	IEC1287, $V_1 = 6900V$ , $V_2 = 5100V$ , 50Hz RMS	10	рС

#### THERMAL AND MECHANICAL RATINGS

Internal insulation material:	AIN
Baseplate material:	AlSiC
Creepage distance:	56mm
Clearance:	26mm
CTI (Comparative Tracking Index):	> 600

Symbol	Parameter	Test Conditions	Min	Тур.	Мах	Units
R <sub>th(j-c)</sub>	Thermal resistance (per arm)	Continuous dissipation – junction to case	-	-	16	°C/kW
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink (per module)	Mounting torque 5Nm (with mounting grease)	-	-	8	°C/kW
Tj	Junction temperature		-40	-	125	°C
T <sub>stg</sub>	Storage temperature range		-40	-	125	°C
		Mounting – M6	-	-	5	Nm
	Screw Torque	Electrical connections – M8	-	-	10	Nm

## STATIC ELECTRICAL CHARACTERISTICS – PER ARM

T<sub>case</sub> = 25°C unless stated otherwise.

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
I <sub>RM</sub>	Peak reverse current	$V_R = 4500V, T_j = 125^{\circ}C$			90	mA
V <sub>F</sub>	Forward voltage	I <sub>F</sub> = 1200A		2.8		V
		I <sub>F</sub> = 1200A, T <sub>j</sub> = 125°C		3.2		V
L <sub>M</sub>	Inductance	-		40		nH

## DYNAMIC ELECTRICAL CHARACTERISTICS – PER ARM

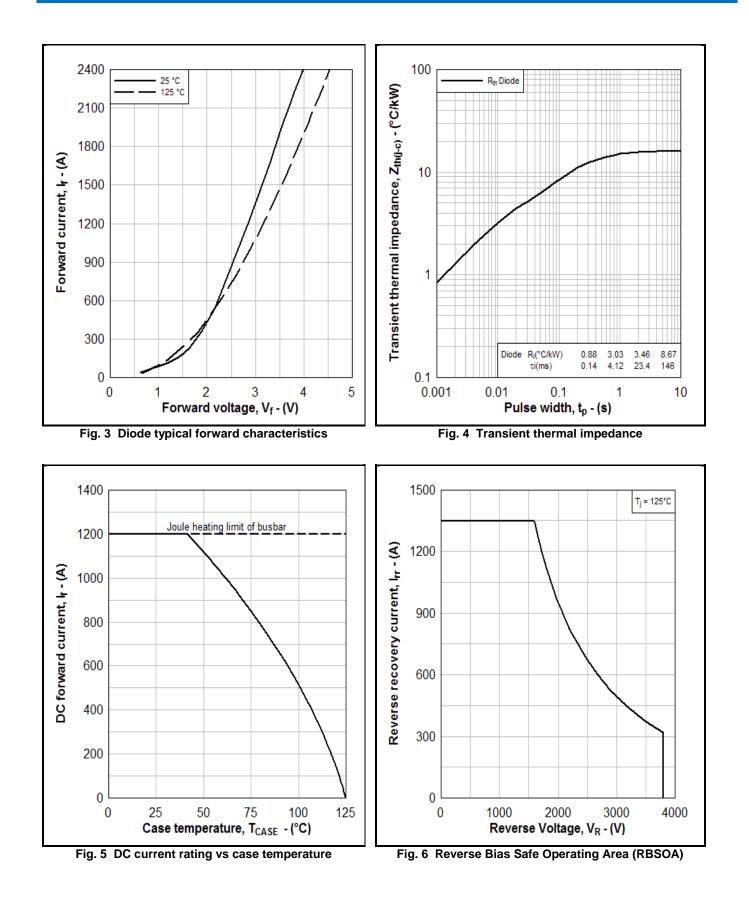
#### T<sub>case</sub> = 25°C unless stated otherwise (when used with DIM1200ASM45-TS001)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q <sub>rr</sub>	Reverse recovery charge	I <sub>F</sub> = 1200A		1340		μC
l <sub>rr</sub>	Peak reverse recovery current	· · · · ·		1030		А
E <sub>rec</sub>	Reverse recovery energy	dI <sub>F</sub> /dt = 3000A/µs		2200		mJ

#### T<sub>case</sub> = 125°C unless stated otherwise (when used with DIM1200ASM45-TS001)

Symbol	Parameter	Test Conditions	Min	Тур.	Max	Units
Q <sub>rr</sub>	Reverse recovery charge	I <sub>F</sub> = 1200A		2200		μC
l <sub>rr</sub>	Peak reverse recovery current	V <sub>R</sub> = 2800V		1100		А
E <sub>rec</sub>	Reverse recovery energy	dI <sub>F</sub> /dt = 3200A/µs		3750		mJ

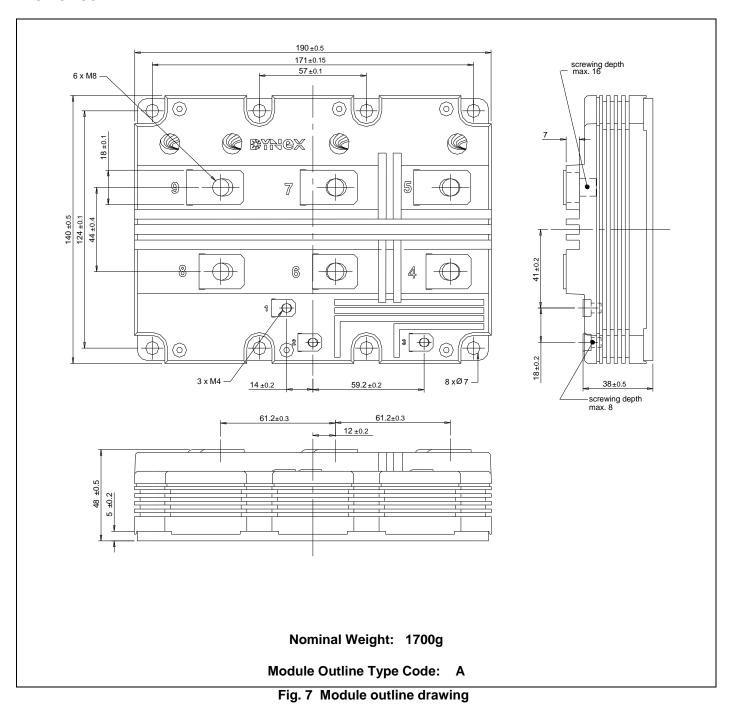






#### PACKAGE DETAILS

For further package information, please visit our website or contact Customer Services. All dimensions in mm, unless stated otherwise. **DO NOT SCALE.** 





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